## Outline：

The BL8532B is a PFM Step－up DC／DC driver IC with invariant current，design for LED applications．Thought the external resistance， output current reach $0 \mathrm{~mA} \sim 500 \mathrm{~mA}$ ．

A low ripple，high efficiency step－up DC／DC converter can be constructed of BL8532Bxx with only three external components．Also available is a CE（chip enable）function that reduce power consumption
reduce power consumpion

## Features：

－Low start voltage： 0.8 V （ at lout＝1mA）；
－Output Current range：0～500mA；
－Output Current accuracy：$\pm 10 \%$ ；
－High Efficiency：82\％（Type）；
－PACKAGE：SOT－89－5．

## Applications：

－Power source for white LED
－Supply constant current
－Power source for a single or dual－cell battery－powered equipments

## Selection guide：

## Pin configuration：

| BL8532B－$\square \square$ PSN |  |  |
| :---: | :---: | :---: |
| Pin No． | Symbol | Description |
| 1 | IFB | Current feedback pin |
| 2 | Vout | Output pin，power supply for internal circuits |
| 3 | CE | Chip enable pin（active high） |
| 4 | Lx | Switching pin（Nch open drain） |
| 5 | GND | Ground pin |

## Functional block diagram ：



## Absolute maximum ratings：

| PARAMETER | SYMBAL | RATINGS | UNITS |
| :--- | :--- | :--- | :--- |
| VIN Input Voltage | VIN | $0.3 \sim 9$ | V |
| Lx Pin voltage | VLX | $0.3 \sim$ Vout +0.3 | V |
| CE Pin voltage | VCE | $0.3 \sim$ Vout +0.3 | V |
| IFB output voltage | VIFB | $0.3 \sim$ Vout +0.3 | V |
| Lx Pin current | ILX | 1.5 | mA |
| Continuous <br> Total Power <br> Dissipation | SOT－23－5 | Pd | 300 |
| SOT－89－5 | Pd | 500 | mW |
| Maximum Operating Ambient <br> Temperature | Tmax | 150 | ${ }^{\circ} \mathrm{C}$ |
| Operating Ambient Temperature | TOpr | $-20 \sim+85$ | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | Tstg | $-40 \sim+125$ | ${ }^{\circ} \mathrm{C}$ |
| Soldering temperature and time | Tsolder | $260{ }^{\circ} \mathrm{C}, 10 \mathrm{~s}$ |  |

## Recommended operating conditions：

|  | MIN | NOM | MAX | UNIT |
| :--- | :---: | :---: | :---: | :---: |
| Input voltage range | 0.8 |  | Vout | V |
| inductor | 10 | 15 | 100 | $\mu \mathrm{H}$ |
| Input capacitor | 0 | $\geqslant 22$ |  | $\mu \mathrm{~F}$ |
| Output capacitor＊ | 47 | 100 | 220 | $\mu \mathrm{~F}$ |
| Operating junction temperature | -20 |  | 85 | ${ }^{\circ} \mathrm{C}$ |

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## Electrical characteristics：

（Vin＝2．5V， $\mathrm{V}_{\text {CE }}=$ Vout $=3.3 \mathrm{~V}, \mathrm{R}=33 \Omega, \mathrm{TA}=25^{\circ} \mathrm{C}$ ，unless otherwise noted．）

| Symbol | Item | Test conditions | Min | Typ． | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VOUT | feedback Voltage | IOUT $=100 \mathrm{~mA}$ | 90 | 100 | 110 | mV |
|  |  |  | 180 | 200 | 220 |  |
| Vstart | Starup Voltage | IOUT＝1mA， <br> VIN： $0 \rightarrow 2 \mathrm{~V}$ |  | 0.8 | 0.9 | V |
| Vhold | holding Voltage | IOUT $=1 \mathrm{~mA}$ ， <br> VIN： $2 \rightarrow 0 \mathrm{~V}$ | 0.6 | 0.9 |  | V |
| IDD2 | Supply Current | $\begin{gathered} \text { LX empty, } \\ \text { VCE=VIFB }=\text { VOUT }=3.3 \\ \text { V } \end{gathered}$ |  | 36 |  | $\mu \mathrm{A}$ |
| ILX | Lx Switching Current | VLX $=0.4 \mathrm{~V}$ ，VIFB＝0 | 700 |  |  | mA |
| ILXIeak | Lx Leakage Current | VOUT＝VLX＝VIFB＝6V |  |  | 1 | $\mu \mathrm{A}$ |
| Ileak | CE is＂L＂， Leakage Current of the chip | VOUT=3.3V, VCE=0, <br> LX，IFB empty |  | ＜0．1 | 0.5 | $\mu \mathrm{A}$ |
| Fosc | Oscillation Frequency | VIFB＝0 |  | 300 |  | kHz |
| Maxdty | Duty Ratio | On（VLX＂L＂）side | 77 | 79 | 82 | \％ |
| $\eta$ | Efficiency | IOUT $=250 \mathrm{~mA}$ |  | 82 |  | \％ |
| VCEH | CE is＂ H ＂，input voltage | VCE： $0 \rightarrow 2 \mathrm{~V}$ <br> （up to work slowly with the chip） | 0.6 | 0.9 |  | V |
| VCEL | $C E$ is＂ L ＂，input voltage | VCE： $0 \rightarrow 2 \mathrm{~V}$ （down to work off slowly with the chip） |  | 0.3 | 0.6 | V |
| IOM | Maximum output diver power | VIFB $=0$ ，VOUT $=3.3 \mathrm{~V}$ |  | 500 |  | mA |

## Note：

1，Diode：Schottky diode（forward voltage drop：0．3V，0．3A），such as IN5817 or 1 N5819
2．Inductor： $15 \mu \mathrm{H}$（ $\mathrm{R}<0.5 \Omega$ ）
3，Capacitor： $100 \mu \mathrm{~F}$（Tantalum type ）
4，VIFB（SET）is feedback voltage of the chip set up ，is the first parameter of the table ，such as $100 \mathrm{mV}, ~ 200 \mathrm{mV}$ and so on．

## Typical applications：

Constant output current application

（A）Drive only one white LED

（B）Drive two white－LED in series and several in parallel connection

## Suggestions：

1．you can increase the output capacitor properly for improve to the characteristic of the output invariant current（ for example：150uF or 200uF）．

2．to avoid the feedback voltage excursion，please wear the ring with static electricity and the electric iron connect to ground when the soldering

## Detailed description：

The BL8532B is a DC／DC step－up converter with voltage type，PFM control mode ， output invariablenes current．It has only three Peripheral components that is a inductor ，a output capacitor，a schottky diode and a resistor with set－up output current，that can afford to a invariant output current between 0 and 500 mA ．

Rc set－up method：
If the output current is lout，that $\mathrm{R} \mathrm{C}=V_{\text {IFB }} /$ Iout 。

For example，want to the current value of 100 mA ，select the chip of VIFB $=200 \mathrm{mV}$ ， that $\mathrm{Rc}=200 \mathrm{mV} / 100 \mathrm{~mA}=2 \Omega$ 。

## Selection of the external components：

Thus it can be seen，the inductor and shottky diode affect the conversion efficiency greatly． The inductor and the capacitor also have great influence on the output voltage ripple of the converter．So it is necessary to choose a suitable inductor，a capacitor and a right shottky diode， to obtain high efficiency，low ripple and low noise．

Before discussion，we define：$D \equiv \frac{\text { Vout }- \text { Vin }}{\text { Vout }}$ ．

## Inductor Selection

Make sure DC－DC can natural work firstly in the model of the minimum continuous current that is $L \min , \quad L \min \geqq \frac{D(1-D)^{2} R_{L}}{2 f}$
This formula deduce that ignoring the autoecious resistor and a diode with the forward voltage drop，but the actual value is still big．If the inductance less than Lmin，inductor will reach magnetic saturation，efficiency will greatly drop，and hardly output steady voltage．
Secondly，considering the current ripple of the inductor，ignoring the autoecious parameter in the mode of continuous current．

$$
\Delta \mathrm{I}=\frac{D \bullet \operatorname{Vin}}{L f}, \quad \operatorname{Imax}=\frac{\operatorname{Vin}}{(1-D)^{2} R_{L}}+\frac{D \operatorname{Vin}}{2 L f} .
$$

When＂ L ＂is too small，will lead to high current ripple of the inductor，and the maximum current of the inductor，schottky diode，power tube of the chip are excessive ．

Thirdly，generally speaking，not considering efficiency，small inductor can drive load more then large inductor ．But in the same load conditions，large inductor with the current ripple and the maximum current value are small．So the large inductor should be able to start up circuit in the low input voltage．

Use inductor with an inductance of $10 \mu \mathrm{H}$ or more，it＇s ensure to normal work．If output port has load with output large current（for example：output current is more than 50 mA ），for improving to efficiency，suggest to use large inductor．At the same time，in the large load，the resistor is in series with the inductor that will affect the switching efficiency．Supposed，the resistor is rL ，Rload，that the power consumption as follow：

$$
\Delta \eta \approx \frac{r_{L}}{R_{\text {load }}(1-D)^{2}}
$$

For example，input 1.5 V ，output 3.0 V ，load $20 \Omega(150 \mathrm{~mA})$ ，rL＝0．5 2 ，efficiency loss $10 \%$ ． Considering，suggest to use an inductance of $15 \mathrm{uH},<0.5 \Omega$ ．

## （2）Capacitor Selection

No considering the inductor with equivalent series resistor（ESR），output voltage ripple is：

$$
\mathrm{r}=\frac{\Delta \text { Vout }}{\text { Vout }}=\frac{D}{R_{\text {load }} C f}
$$

considering the inductor＇s ESR，the output ripple will be increase：

$$
r^{\prime}=r+\frac{\operatorname{Im} a x \bullet R_{E S R}}{\text { Vout }}
$$

Suggest to use Tantalum type with the low ESR or more parallel－resistor．

## （3）Diode Selection

It is recommended that the diode have great effect to DC－DC efficiency，we suggest to use schottky diode with the lower positive turn－on voltage and the lower corresponsive time．For example，1N5817，1N5819．

## （4）Input Capacitor

Power supply is stably，even if no input capacitor，DC－DC can output voltage with the lower ripple and the lower noise．But we suggest to connect with the capacitor of 10uF or more when the power supply was far away DC－DC，for minish the output noise．

## （5）Resistor R1，R2 for output voltage detect

Application to invariant current ，the formula of R1，R2：

$$
\frac{\text { Vout }}{V_{I F B}}=\frac{R 1}{R 2}+1
$$

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## Test circuits：

（1）Feedback voltage test circuit

（2）Start－up voltage test circuit（ $I_{\text {load }}=1 \mathrm{~mA}$ ）

（3）Hold－on voltage test circuit（ $I_{\text {load }}=1 \mathrm{~mA}$ ）

（4）Quiescent current test circuit

（5）Oscillator frequency and duty cycle test circuit

（6）LX switching current test circuit

（7）LX leakage current test circuit

（8）CE＂ H ＂voltage test circuit

（9）CE＂L＂voltage test circuit


Package description：


Brede size：
Mode（1）is the standard package；
Mode（2）is customized for client．



